

Low Input Voltage 500mA LDO

General Description

The ET552XXY1B is a low input voltage 500mA LDO. The input voltage is as low as Min. 1.2V. The output voltage accuracy has been improved to $\pm 2\%$ and due to a built-in transistor with low on-resistance. It consists of a voltage reference unit, an error amplifier, a resistor-net for voltage setting, and a current limit circuits for over-current prevention.

The ET552XXY1B uses a type of outstanding CMOS process to minimize the supply current. A low on-resistance PMOS pass device is equipped for lower dropout voltage. ET552XXY1B also possess the CE function to save more energy and extend the battery life. The CE pin can switch the regulator to standby mode.

Features

- Wide Input Voltage Range: 1.2V to 5V
- Fixed Output Voltage : 0.6V, 0.85V, 0.9V, 1.0V, 1.05V, 1.1V, 1.8V and etc
- Other Voltage Can Be Provided According to Demand: 0.6V~3.6V Range
- Very Low IQ: 55 μ A
- Up to 500mA Load Current
- Output Voltage Accuracy: $\pm 2\%$
- Dropout Voltage: Typ. 0.43V(500mA) @1.1V Output
- Excellent Load/Line Transient Response
- Line Regulation: 0.1%/V (typical)
- Built-in Fold Back Protection Circuit
- Built-in Constant Slope Circuit
- Built-in Auto-discharging Circuit
- Built-in Thermal Protection Circuit
- Package No. and MSL Level:

Part No.	Package	Packing Option	MSL
ET552XXY1B	DFN4(1 $\times$ 1)	Tape and Reel, 10K/Reel	1

Applications

- Constant-Voltage Power Supply for Battery-powered Device
- Constant-Voltage Power Supply for TV, Notebook PC and Home Electric Appliance
- Constant-Voltage Power Supply for Portable Equipment

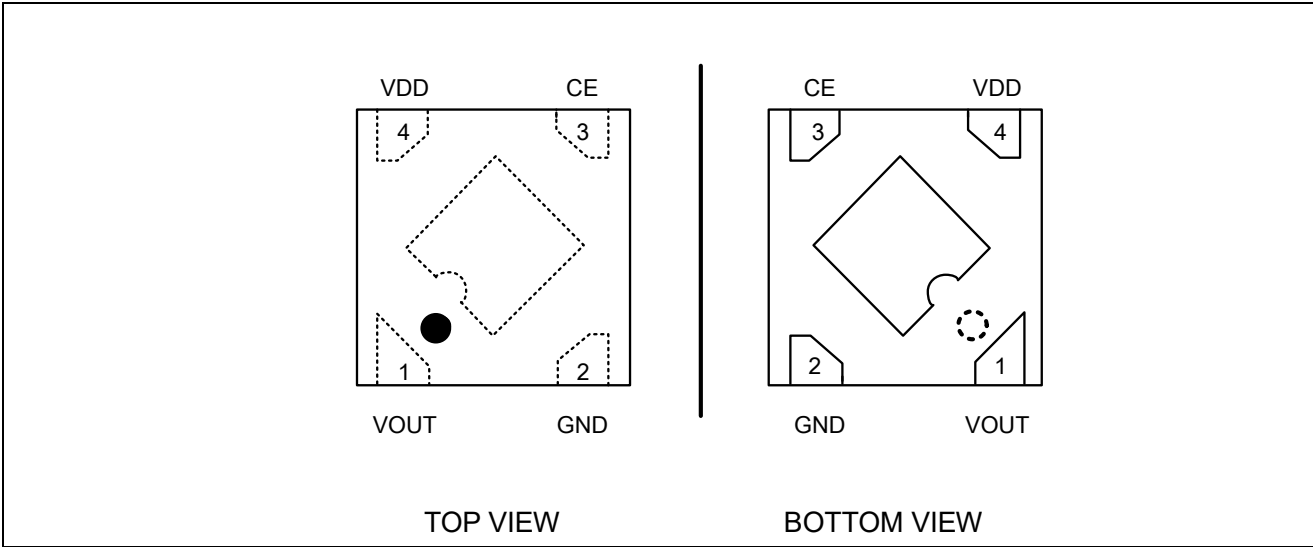
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Device Information

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<u>XX</u> Output Voltage		<u>Y1</u> Package		<u>B</u> Auto-Discharging Function	
XX	Fixed Output Voltage, For example, 12 is 1.2V	Y1	DFN4(1×1)	B	Available

Pin Configuration

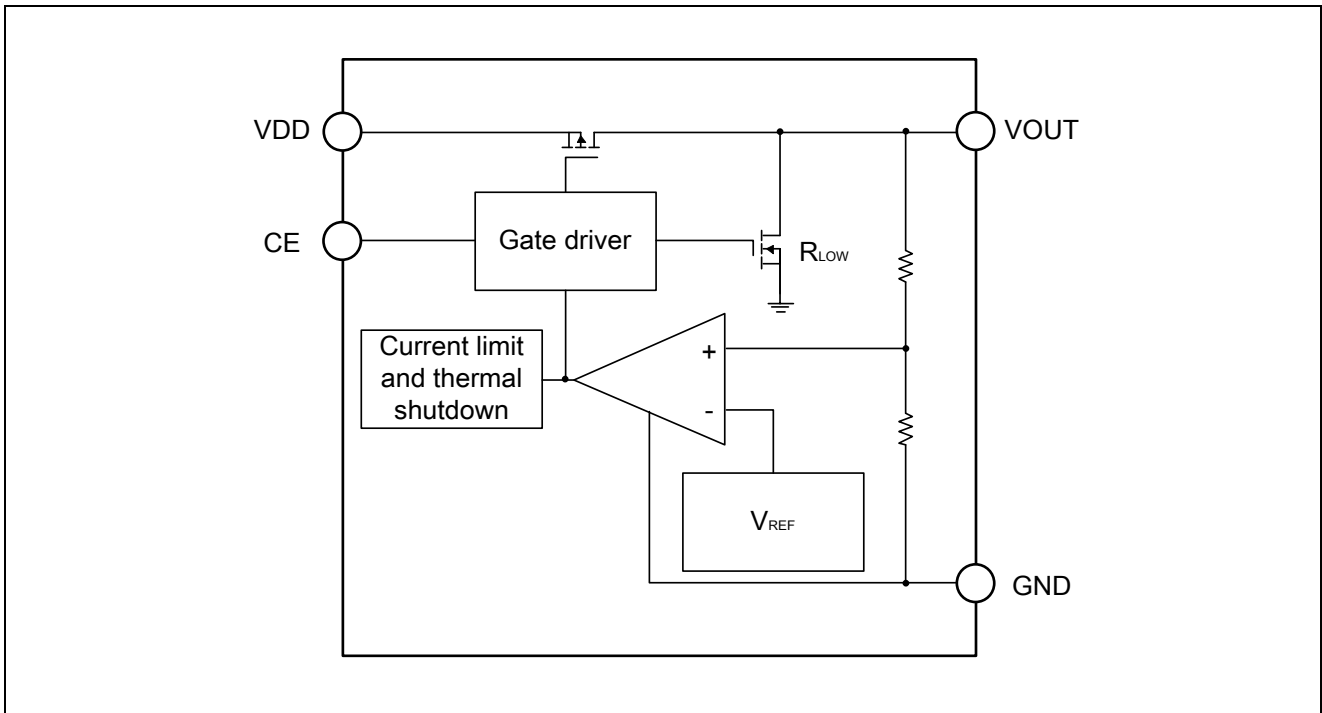


Pin Function

Pin No.	Pin Name	Pin Function
1	VOUT	Output Pin
2	GND	Ground Pin
3	CE	Chip Enable Pin, “H” Enable
4	VDD	Input Pin
-	Thermal Pad	Thermal pad for DFN4(1×1) package, connect to GND.

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Block Diagram



Functional Description

Input Capacitor

A 1 μ F ceramic capacitor is recommended to connect between V_{DD} and GND pins to decouple input power supply glitch and noise. The amount of the capacitance may be increased without limit. This input capacitor must be located as close as possible to the device to assure input stability and less noise. For PCB layout, a wide copper trace is required for both V_{DD} and GND.

Output Capacitor

An output capacitor is required for the stability of the LDO. The recommended output capacitance is 0.47 μ F to 10 μ F (usually 1 μ F), Equivalent Series Resistance (ESR) is from 5m Ω to 100m Ω . Ceramic capacitor is recommended, and temperature characteristics are X7R or X5R. Higher capacitance values help to improve load/line transient response. The output capacitance may be increased to keep low undershoot/overshoot. Place output capacitor as close as possible to V_{OUT} and GND pins.

CE Pin Operation

The ET552XXY1B is turned on by setting the CE pin to "H". The CE pin do not set it in floating status. When the CE pin is not used, connect the CE pin with V_{DD} to keep the LDO in operating mode.

Current Limit Protection

When output current of V_{OUT} pin is higher than current limit threshold, the current limit protection will be triggered and clamp the output current at a predesigned level to prevent over-current and thermal damage.

Auto Discharging

When the CE pin set to "L", the output circuit will be disable immediately, and the Auto-Discharging circuit will be turned on to discharge the electric charge on output capacitor, and decrease the voltage of V_{OUT} in very

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short time.

Thermal Shutdown Protection

Thermal protection disables the output when the junction temperature rises to approximately +160°C, allowing the device to cool down. When the junction temperature reduces to approximately +140°C the output circuit is enabled again. Depending on power dissipation, thermal resistance, and ambient temperature, the thermal protection circuit may cycle on and off. This cycling limits the heat dissipation of the regulator, protecting it from damage due to overheating.

Absolute Maximum Ratings

Stresses beyond those listed under “Absolute Maximum Ratings” may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other condition beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Parameters	Rating	Unit
Input Voltage	-0.3 to 6.0	V
Input Voltage (CE Pin)	-0.3 to 6.0	V
Output Voltage	-0.3 to $V_{DD}+0.3$	V
Maximum Load Current	500	mA
Maximum Power Consumption	600	mW
Operating Junction Temperature	-40 to 150	°C
Storage Temperature	-65 to 150	°C
Lead Temperature (Soldering, 10 sec)	300	°C
ESD Human Body Model per ESDA/JEDEC JS-001-2017	±4000	V
ESD Charged Device Model per ESDA/JEDEC JS-002-2014	±1500	V

Recommended Operating Conditions

Symbol	Items	Rating	Unit
V_{IN}	Input Voltage	1.2 to 5.0	V
I_{OUT}	Output Current	0 to 500	mA
T_A	Operating Ambient Temperature	-40 to 85	°C
C_{IN}	Effective Input Ceramic Capacitor Value	0.47 to 10	μF
C_{OUT}	Effective Output Ceramic Capacitor Value	0.47 to 10	μF
ESR	Input and Output Capacitor Equivalent Series Resistance (ESR)	5 to 100	mΩ

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Electrical Characteristics

(Unless otherwise noted, $V_{IN}=V_{OUT}+1V$, $T_A=25^{\circ}C$, unless otherwise stated, $C_{IN}=C_{OUT}=1\mu F$)

Symbol	Parameters	Conditions	Min	Typ	Max	Unit
$V_{IN}^{(1)}$	Operating Input Voltage Range		1.2		5.0	V
$V_{DROP}^{(2)}$	Dropout Voltage	$V_{OUT} = 0.6V, I_{OUT} = 500mA$		700	900	mV
		$V_{OUT} = 0.6V, I_{OUT} = 300mA$		400	600	mV
		$V_{OUT} = 0.85V, I_{OUT} = 500mA$		600	825	mV
		$V_{OUT} = 0.85V, I_{OUT} = 300mA$		360	495	mV
		$V_{OUT} = 0.9V, I_{OUT} = 500mA$		600	825	mV
		$V_{OUT} = 0.9V, I_{OUT} = 300mA$		360	495	mV
		$V_{OUT} = 1.0V, I_{OUT} = 500mA$		430	575	mV
		$V_{OUT} = 1.0V, I_{OUT} = 300mA$		255	345	mV
		$V_{OUT} = 1.1V, I_{OUT} = 500mA$		430	575	mV
		$V_{OUT} = 1.1V, I_{OUT} = 300mA$		255	345	mV
		$V_{OUT} = 1.8V, I_{OUT} = 500mA$		240	375	mV
		$V_{OUT} = 1.8V, I_{OUT} = 300mA$		140	245	mV
I_{Q_ON}	DC Supply Quiescent Current	Active mode: $V_{CE} = V_{IN}$	30	55	70	μA
I_{Q_OFF}	DC Supply Shutdown Current	$V_{CE} = 0V$		0.1	2	μA
V_{OUT}	Output Voltage	$I_{OUT} = 1mA \sim 500mA$, $T_A = 25^{\circ}C$	-2		2	%
		$I_{OUT} = 1mA$, $T_A = -40^{\circ}C \sim 85^{\circ}C$	-2.5		2.5	
Reg_{LINE}	Output Voltage Line Regulation	$V_{OUT}+1V \leq V_{IN} \leq 5V$, $I_{OUT} = 10mA$ ($\Delta V_{OUT}/\Delta V_{IN}/V_{OUT}$)		0.10	0.25	%/V
Reg_{LOAD}	Output Voltage Load Regulation	I_{OUT} from 1mA to 500mA (ΔV_{OUT})		25	45	mV
$V_{TRLN}^{(3)}$	Line Transient (The absolute value of the output change)	$I_{OUT} = 1mA$, $V_{IN} = V_{OUT}+1V$ to 5V in 10us, $T_A=25^{\circ}C$		15	30	mV
		$I_{OUT} = 1mA$, $V_{IN} = 5V$ to $V_{OUT}+1V$ in 10us, $T_A=25^{\circ}C$		15	30	
$V_{TRLD}^{(3)}$	Load Transient (The absolute value of the output change)	$V_{IN} = V_{OUT}+1V$, I_{OUT} from 1mA to 500mA in 10us, $T_A = 25^{\circ}C$		85	120	mV
		$V_{IN} = V_{OUT}+1V$, I_{OUT} from 500mA to 1mA in 10us, $T_A = 25^{\circ}C$		50	120	
I_{OUT}	Output Current		500			mA
I_{LMT}	Over Current Limit	$V_{IN} = V_{OUT}+1V$, $T_A = 25^{\circ}C$	600	700	900	mA

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Electrical Characteristics(continues)

(Unless otherwise noted, $V_{IN}=V_{OUT}+1V$, $T_A=25^{\circ}C$, unless otherwise stated, $C_{IN}=C_{OUT}=1\mu F$)

Symbol	Parameters	Conditions	Min	Typ	Max	Unit
I_{SHORT}	Short Current Limit	$V_{OUT} = 0V$, $T_A = 25^{\circ}C$	70	110	180	mA
$PSRR^{(3)}$	Power Supply Rejection Ratio	$f = 1kHz$, $C_{OUT} = 1\mu F$, $I_{OUT} = 20mA$, $V_{IN} = V_{OUT}+1V$, $T_A = 25^{\circ}C$	50	80		dB
$e_N^{(3)}$	Output Noise	10Hz to 100kHz, $I_{OUT} = 30mA$, $C_{OUT} = 1\mu F$, $T_A = 25^{\circ}C$		40	70	μV_{RMS}
V_{ENL}	EN Low Threshold	$V_{IN}=1.2$ to $5V$			0.4	V
V_{ENH}	EN High Threshold	$V_{IN}=1.2$ to $5V$	0.9			V
I_{CE}	CE Pull-down Current	$V_{IN} = V_{CE} = V_{OUT}+1V$, $T_A = 25^{\circ}C$	0.2	0.7	1	μA
R_{LOW}	Output resistance of auto discharge at off state	$V_{EN} = 0V$, $V_{IN} = 2V$, $I_{OUT} = 10mA$	20	40	80	Ω
$T_{SD}^{(4)}$	Thermal Shutdown Temperature	Junction Temperature		160		$^{\circ}C$
$T_{SR}^{(4)}$	Thermal Shutdown Temperature, released	Junction Temperature		140		$^{\circ}C$

Note1: Here V_{IN} means internal circuit can work normal. If $V_{IN} < V_{OUT}$, Output voltage follow $V_{IN}(I_{OUT}=1mA)$, circuit is safety. The maximum input voltage should take into account the maximum power consumption (PD(max)). The calculation formula is as follows:

$$PD_{(MAX)} = (V_{IN(MAX)} - V_{OUT}) * I_{OUT}$$

The maximum power consumption of the circuit is 600mW.

$$V_{IN(MAX)} = 600mW / I_{OUT} + V_{OUT}$$

For example:

If $I_{OUT}=500mA$, $V_{OUT}=1.05V$, the maximum input voltage is $V_{IN(max)}=600mW/500mA+1.05=2.25V$.

Note2: V_{DROP} list $I_{OUT} = 300mA \& 500mA$ here.

Note3: Guaranteed by design and characterization. not a FT item.

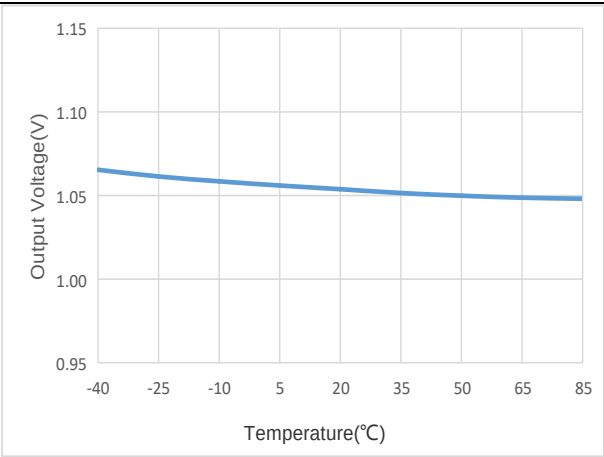
Note4: Guaranteed by design . Not a FT item.

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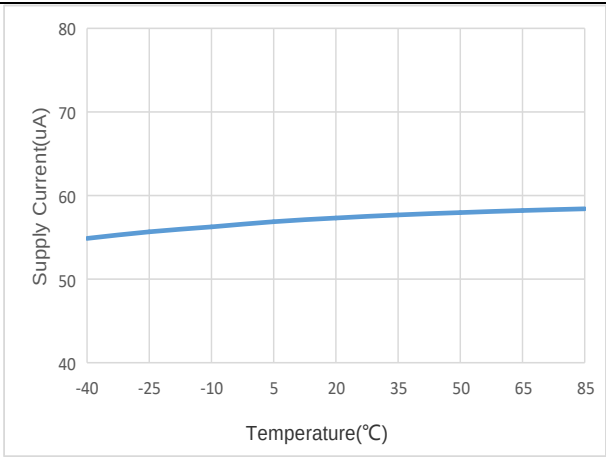
Typical Characteristics

(1) VOLTAGE VERSION 1.05 V

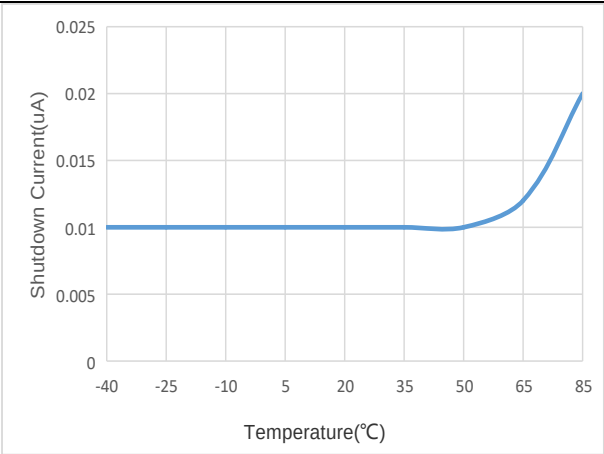
($V_{OUT}=1.05V$, $V_{IN}=2.05V$, $C_{IN}=C_{OUT}=1\mu F$, $T_A=25^{\circ}C$, unless otherwise stated)



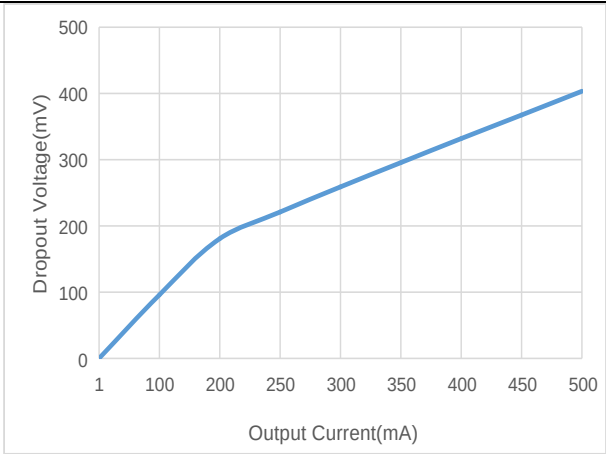
Output Voltage VS Temperature



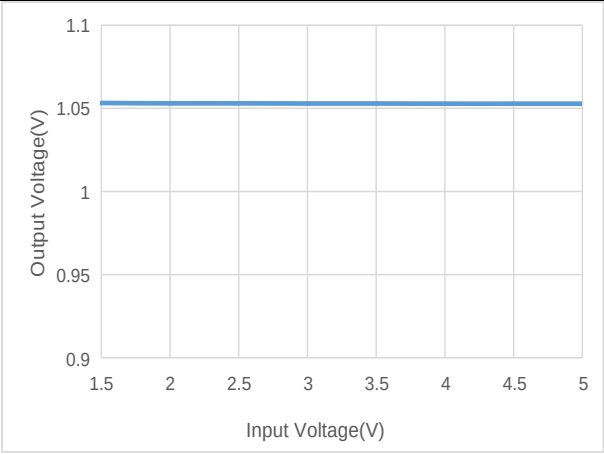
Supply Current VS Temperature



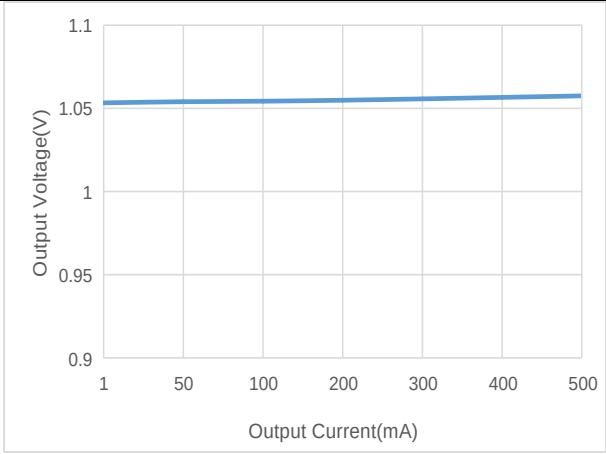
Shutdown Current VS Temperature



Dropout Voltage VS Output Current

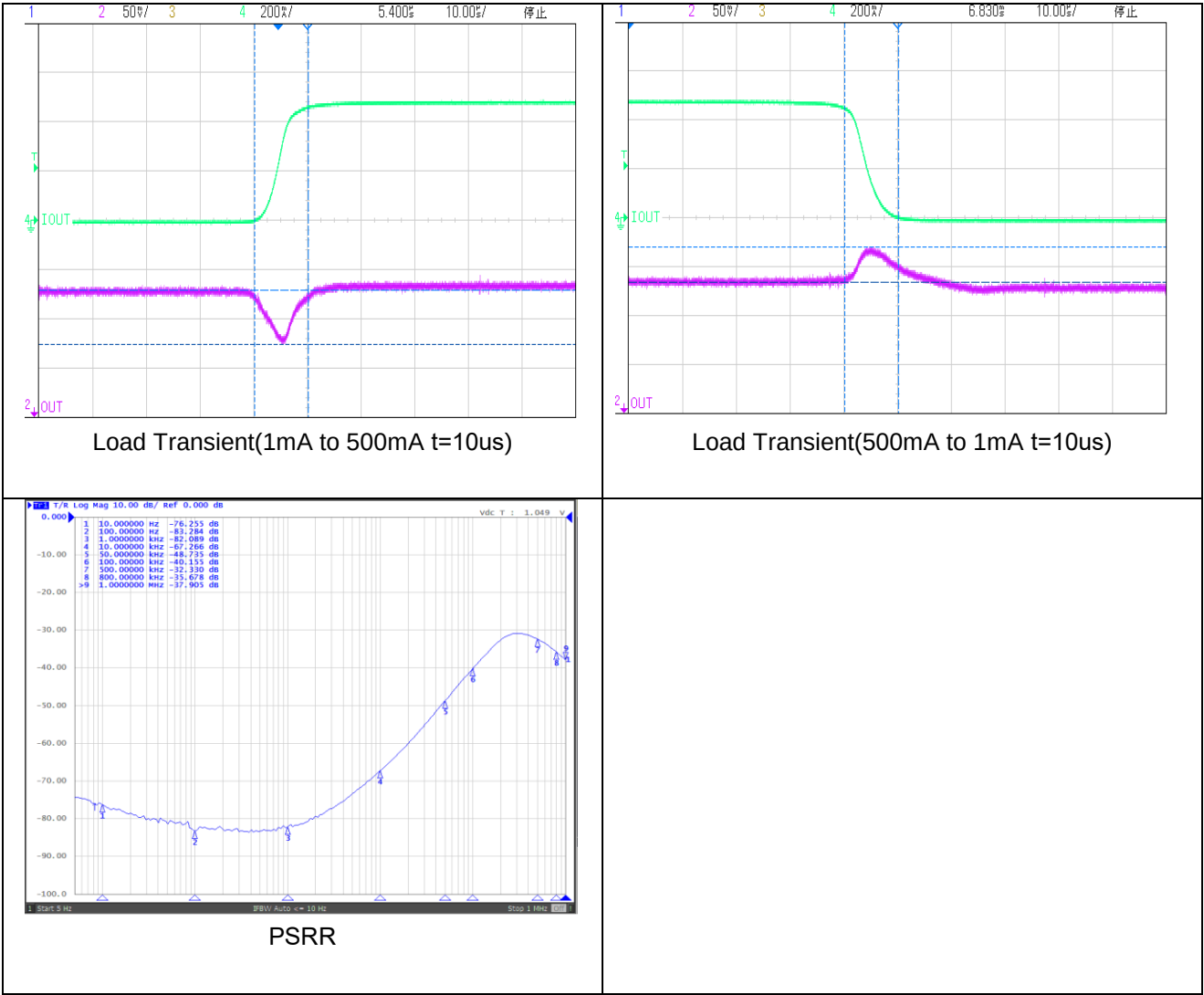


Output Voltage VS Input Voltage



Output Voltage VS Output Current

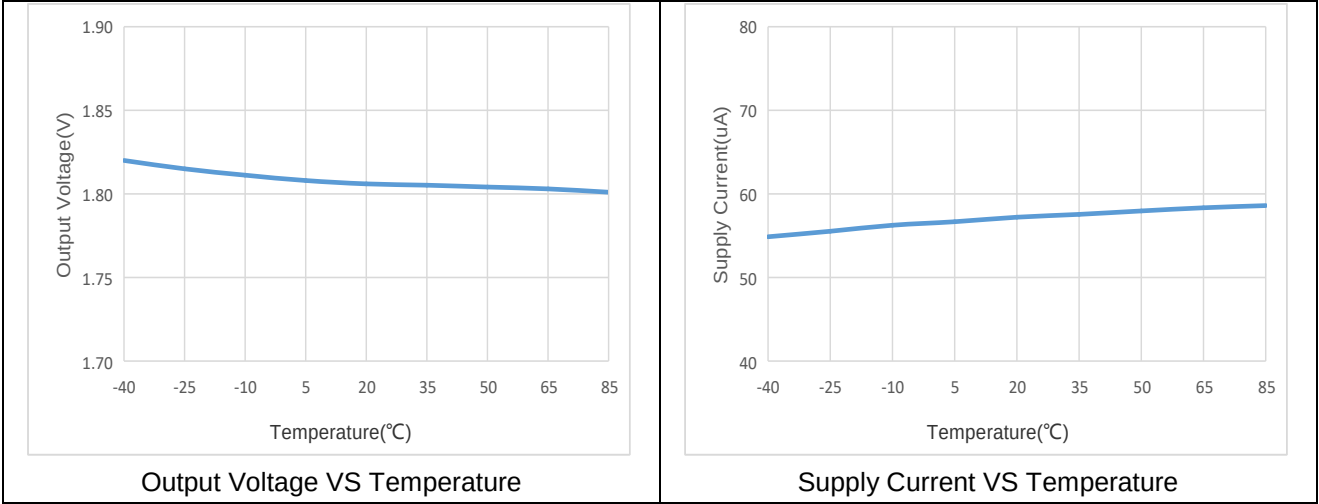
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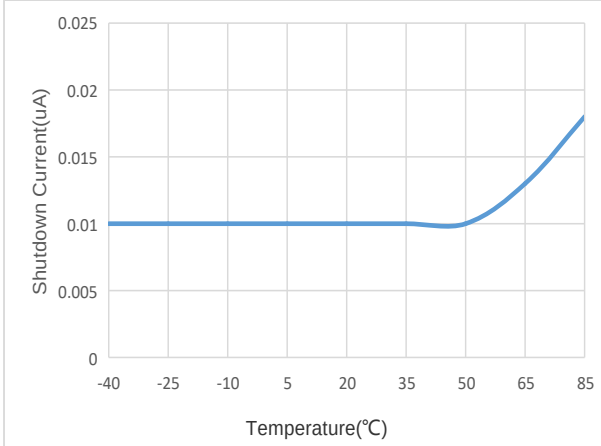
Typical Characteristics

(2) VOLTAGE VERSION 1.8 V

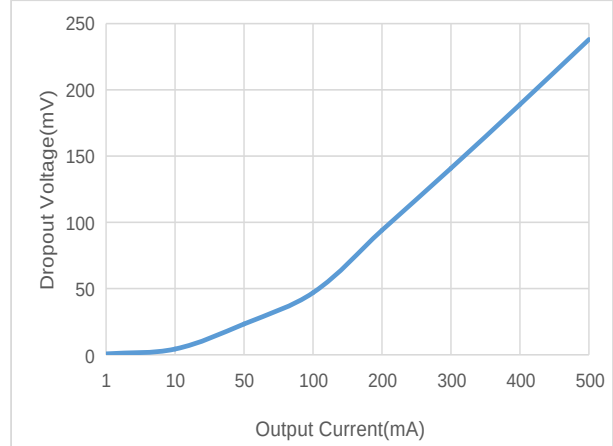
(V_{OUT}=1.8V, V_{IN}=2.8V, C_{IN}=C_{OUT}=1μF, T_A=25°C, unless otherwise stated)



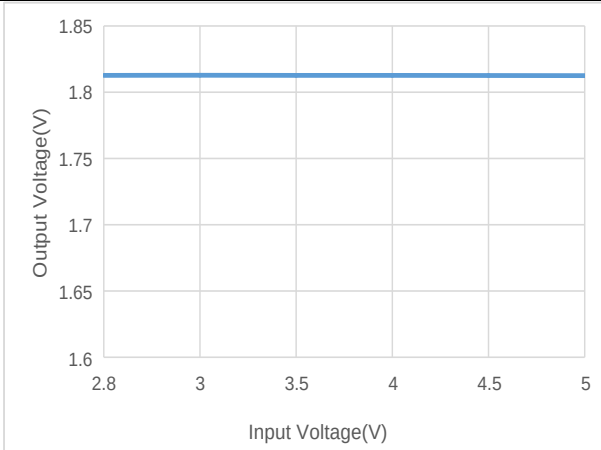
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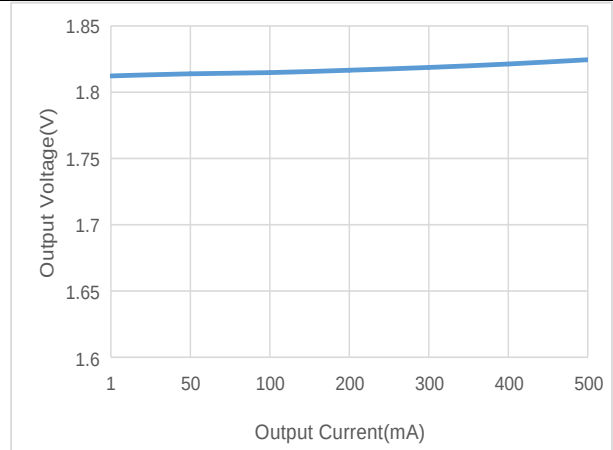
Shutdown Current VS Temperature



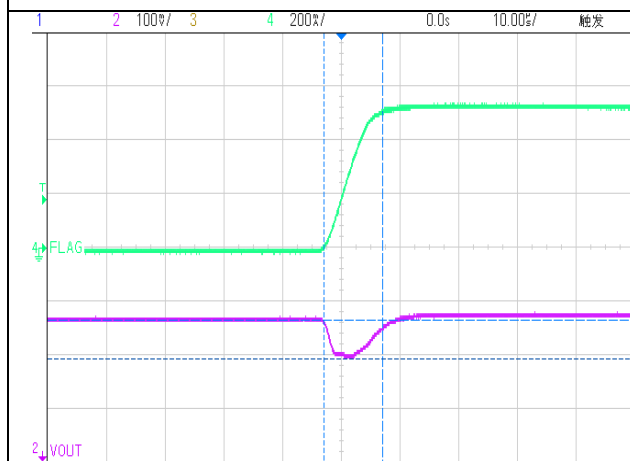
Dropout Voltage VS Output Current



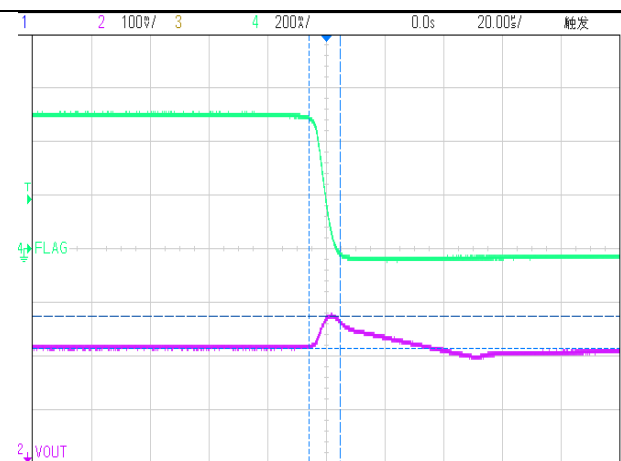
Output Voltage VS Input Voltage



Output Voltage VS Output Current

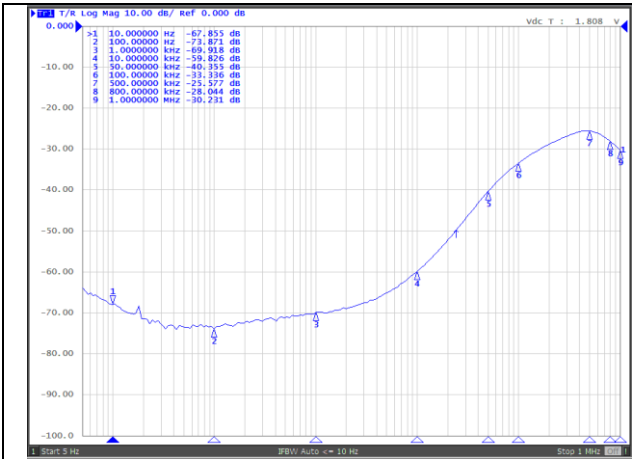


Load Transient(1mA to 500mA t=10us)



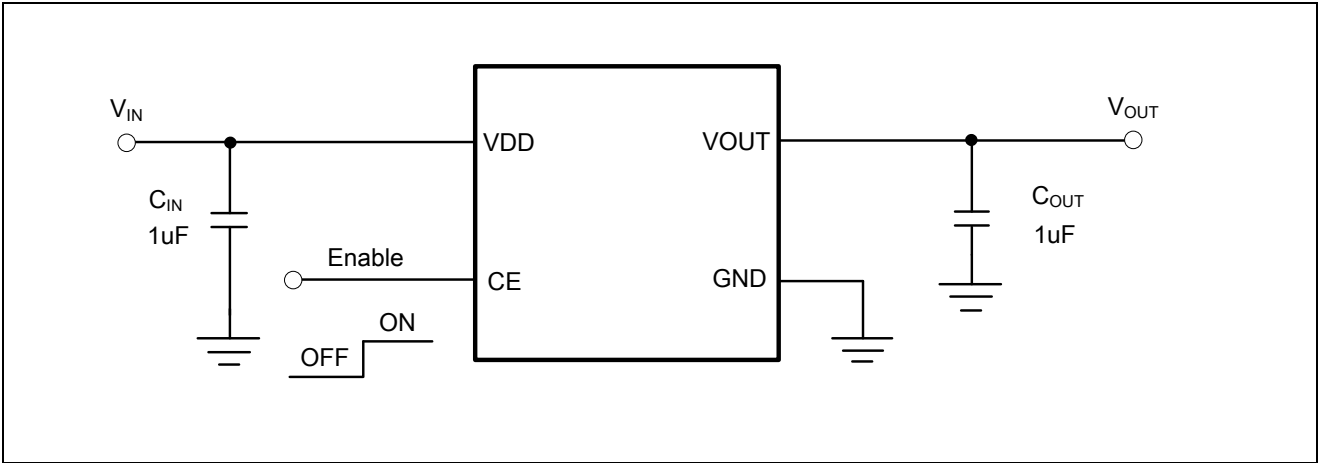
Load Transient(500mA to 1mA t=10us)

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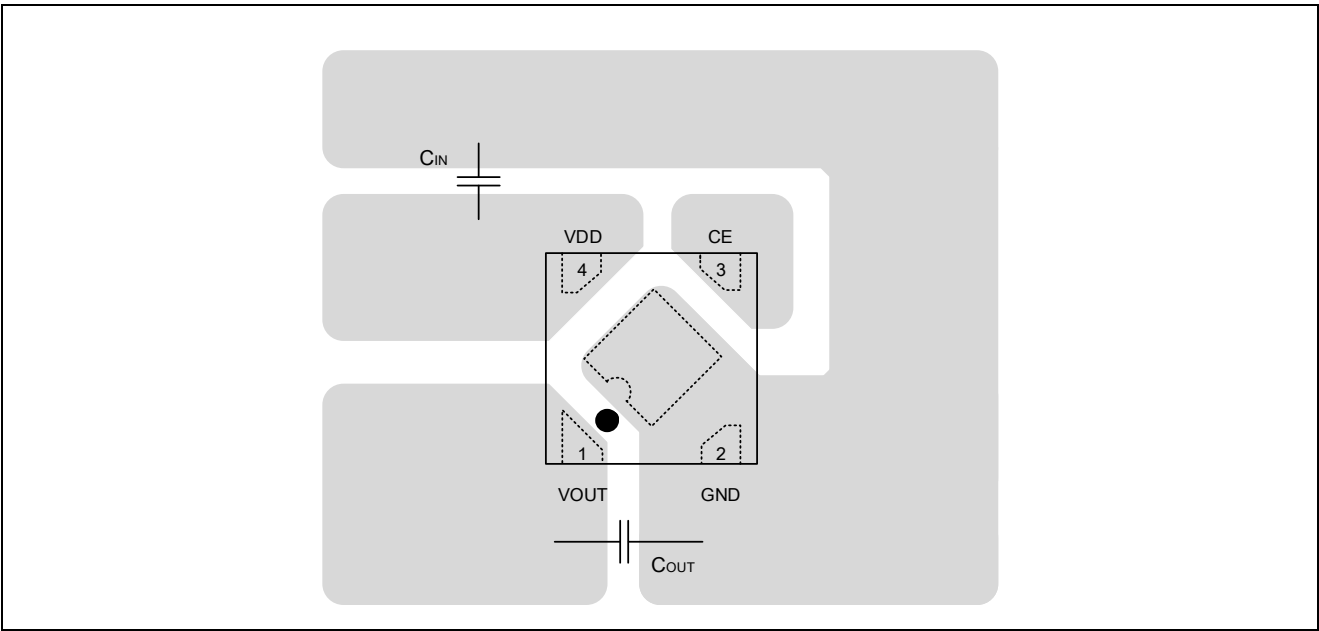


PSRR

Application Circuits

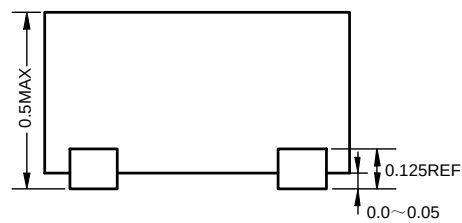
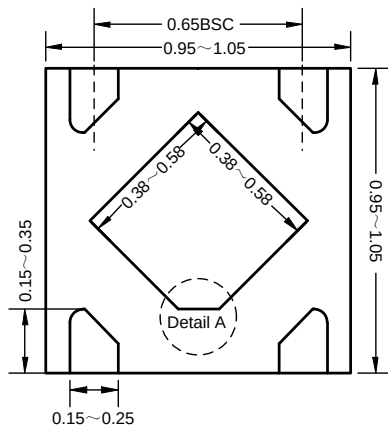


PCB Layout Guide

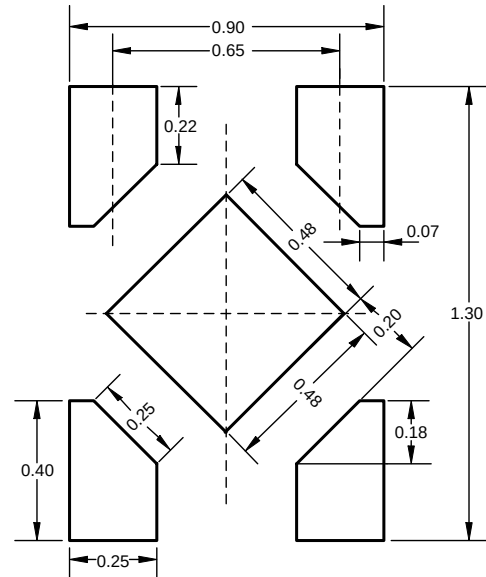
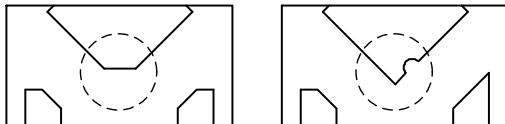


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Package Dimension



Detail A: (PIN1 shape)

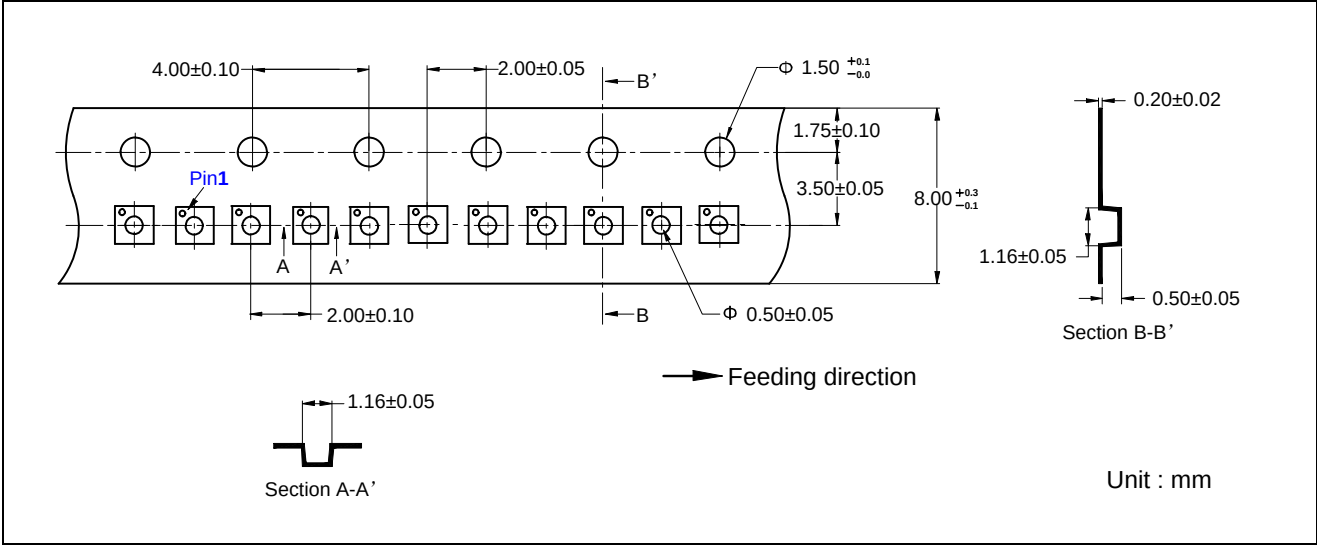


Recommended Land Pattern

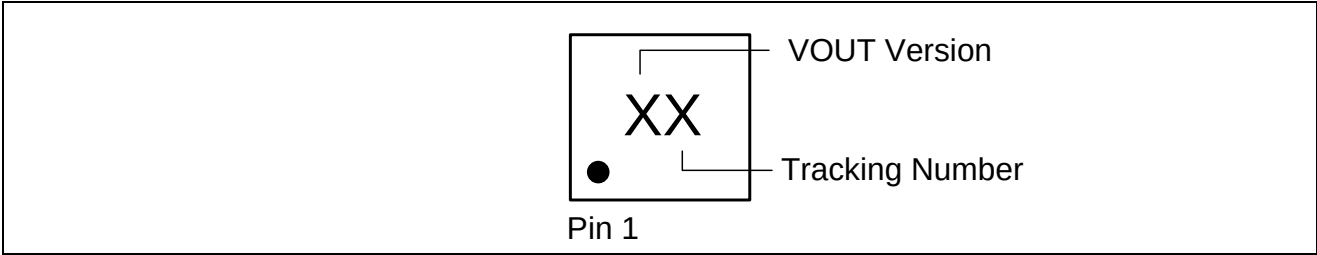
Unit: mm

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Tape Information



Marking



Revision History and Checking Table

Version	Date	Revision Item	Modifier	Function & Spec Checking	Package & Tape Checking
1.0	2019-1-31	Preliminary Version	Liu Yi Guo	Liu Yi Guo	Zhuji
1.1	2019-5-10	Update recommend layout	Shibo	Shibo	Liuji
1.2	2022-11-9	Update recommend layout	Yangzhi	Liu Yi Guo	Zhuji
1.3	2023-10-10	Update package picture	Shibo	Shibo	Liuji
1.4	2024-10-26	Add Tape information	Shibo	Shibo	Liuji